() IDT.

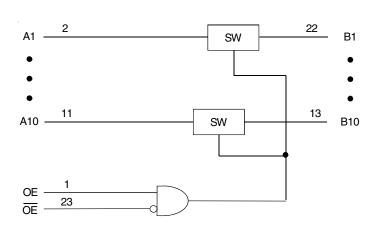
LOW-VOLTAGE 10-BIT BUS SWITCH WITH ACTIVE HIGH AND LOW ENABLES

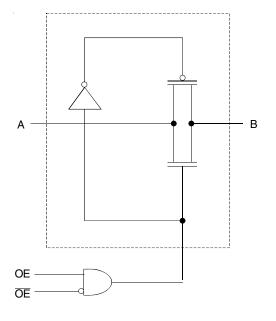
 FEATURES: 5Ω A/B bi-directional switch Isolation Under Power-Off Conditions Over-voltage tolerant Latch-up performance exceeds 100mA Vcc = 2.3V - 3.6V, normal range ESD >2000V per MIL-STD-883, Method 3015; >200V using machine model (C = 200pF, R = 0) Available in QSOP and TSSOP packages 	DESCRIPTION: The CBTLV3862 provides ten bits of high-speed bus switching with low on-state resistance of the switch allowing connections to be made with minimal propagation delay. The device is organized as one 10-bit bus switch. The switches are controlled by independent active-low enable (OE) and active-high enable (OE) controls. To ensure the high-impedance state during power up or power down, OE should be tied to Vcc through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver, and OE should be tied to GND.
APPLICATIONS: • 3.3V High Speed Bus Switching and Bus Isolation	

l

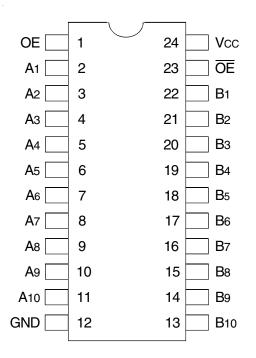
FUNCTIONAL BLOCK DIAGRAM

SIMPLIFIED SCHEMATIC, EACH SWITCH





PINCONFIGURATION



TOP VIEW

Package Type	Package Code	Order Code
TSSOP	PGG24	PGG
QSOP	PCG24	QG

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max.	Unit
Vcc	Vcc Supply Voltage Range		V
VI Input Voltage Range		-0.5 to 4.6	V
	Continuous Channel Current		mA
Ік	Input Clamp Current, VI/o < 0	-50	mA
Tstg	Storage Temperature Range	-65 to +150	°C

NOTE:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

FUNCTION TABLE⁽¹⁾

Inputs			
OE	ŌĒ	Function	
L	L	Disconnect	
L	Н	Disconnect	
Н	L	A Port = B Port	
Н	Н	Disconnect	

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

OPERATING CHARACTERISTICS⁽¹⁾

Symbol	Parameter	Test Conditions	Min.	Max.	Unit
Vcc	Supply Voltage		2.3	3.6	V
Vih	High-Level Control Input Voltage	Vcc = 2.3V to 2.7V	1.7	_	V
		Vcc = 2.7V to 3.6V	2	—	
Vil	Low-Level Control Input Voltage	Vcc = 2.3V to 2.7V	—	0.7	V
		Vcc = 2.7V to 3.6V	—	0.8	
TA	Operating Free-Air Temperature		-40	+85	°C

NOTE:

1. All unused control inputs of the device must be held at Vcc or GND to ensure proper device operation.

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified: Operating Condition: TA = -40° C to $+85^{\circ}$ C

Symbol	Parameter	Test Conditions		Min.	Тур. ⁽¹⁾	Max.	Unit
Vik	Control Inputs, Data I/O	Vcc = 3V, II = -18mA		_	—	-1.2	V
li	Control Inputs, Data I/O	VCC = 3.6V, VI = VCC or GNE)	_	—	±1	μA
loz	Data I/O	VCC = 3.6V, VO = 0V or 3.6V	switch disabled	_	—	5	μA
loff		Vcc = 0V, VI or Vo = 0V or 3	.6V	_	—	50	μA
lcc		VCC = 3.6V, IO = 0, VI = VCC	or GND	_	—	10	μA
$\Delta ICC^{(2)}$	Control Inputs	Vcc = 3.6V, one input at 3V, other inputs at Vcc or GND		_	_	300	μA
Сі	Control Inputs	VI = 3V or 0		_	4	_	pF
CIO(OFF)		Vo = 3V or 0 (switch off)		_	6	_	рF
	VCC = 2.3V	VI = 0	Io = 64mA	_	5	8	
	Typ. at Vcc = 2.5V		lo = 24mA	_	5	8	
Ron ⁽³⁾		VI = 1.7V Io = 15mA VI = 0 Io = 64mA		_	27	40	Ω
				_	5	7	
	Vcc = 3V	lo = 24mA		_	5	7	
		VI = 2.4V	lo = 15mA	_	10	15	

NOTES:

1. Typical Values are at Vcc = 3.3V, +25°C ambient.

2. The increase in supply current is attributable to each input that is at the specified voltage level rather than Vcc or GND.

3. This is measured by the voltage drop between the A and B terminals at the indicated current through the switch.

SWITCHING CHARACTERISTICS

		Vcc = 2	$Vcc = 2.5V \pm 0.2V$		Vcc = 3.3V ± 0.3V	
Symbol	Parameter	Min.	Max.	Min.	Max.	Unit
t _{PD} ⁽¹⁾	Propagation Delay	-	0.15	—	0.25	ns
	A to B or B to A					
ten	Output Enable Time	1	4.5	1	4.2	ns
	OE to A or B					
tois	Output Disable Time	1	5	1	5	ns
	OE to A or B					
ten	Output Enable Time	1	4.5	1	4.2	ns
	OE to A or B					
tois	Output Disable Time	1	5	1	6	ns
	OE to A or B					

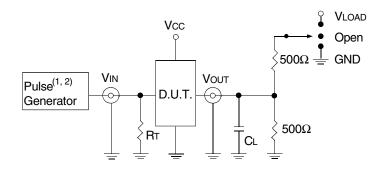
NOTE:

1. The propagation delay is the calculated RC time constant of the typical on-state resistance of the switch and the specified load capacitance when driven by an ideal voltage source (zero output impededance).

TEST CIRCUITS AND WAVEFORMS

TESTCONDITIONS

Symbol	Vcc ⁽¹⁾ =3.3V±0.3V	Vcc ⁽²⁾ =2.5V±0.2V	Unit
VLOAD	6 2 x Vcc		V
Vih	3	3 Vcc	
Vτ	1.5	1.5 Vcc / 2	
Vlz	300	150	
Vhz	300	150	mV
Cl	50	30	pF



Test Circuits for All Outputs

DEFINITIONS:

CL = Load capacitance: includes jig and probe capacitance.

RT = Termination resistance: should be equal to ZOUT of the Pulse Generator.

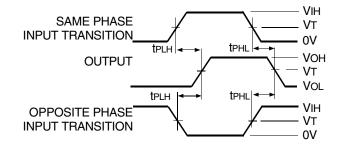
NOTES:

1. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2.5ns; tR \leq 2.5ns.

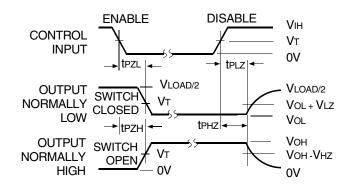
2. Pulse Generator for All Pulses: Rate \leq 10MHz; tF \leq 2ns; tR \leq 2ns.

SWITCH POSITION

Test	Switch
tplz/tpzl	Vload
tpнz/tpzн	GND
ted	Open



Propagation Delay

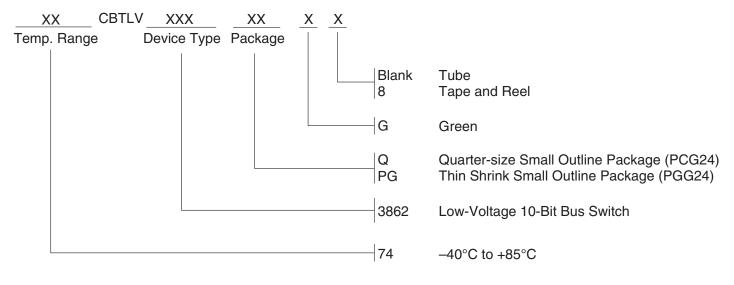


NOTE:

1. Diagram shown for input Control Enable-LOW and input Control Disable-HIGH.

Enable and Disable Times

ORDERING INFORMATION



Orderable Part Information

	Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
7		74CBTLV3862PGG	PGG24	TSSOP	I
		74CBTLV3862PGG8	PGG24	TSSOP	I
		74CBTLV3862QG PCG24 QSOP		I	
		74CBTLV3862QG8	PCG24	QSOP	I

Datasheet Document History

12/18/2014Pg. 504/10/2019Pg. 2,5

Updated the ordering information by removing the "IDT" notation, non RoHS part and by adding Tape and Reel information. Added table under pin configuration diagram with detailed package information and orderable part information table. Updated the ordering information diagram in clearer detail and removed SSOP package.



CORPORATE HEADQUARTERS 6024 Silver Creek Valley Road San Jose, CA 95138 *for SALES:* 800-345-7015 or 408-284-8200 fax: 408-284-2775 www.idt.com *for Tech Support:* logichelp@idt.com